

Low Noise GaAs MMIC Amplifier 2-3 GHz

MAAM23000

Features

- 1.1 dB Typical Noise Figure¹
- 26 dB Typical Gain¹
- On-Chip Bias Network
- DC Decoupled RF Input and Output

Electrical Specifications @ Ta = 25°C

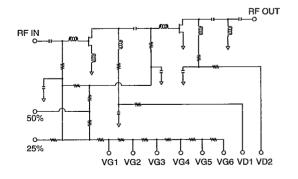
Frequency Range		2.0 – 3.0 GHz	
Gain ¹	26.0 dB Typ	24.0 dB Min	
Gain Flatness		±1.0 dB Typ	
Noise Figure ¹	1.6 dB Max	1.1 dB Typ	
VSWR ¹ Input Output		1.7:1 Typ 1.3:1 Typ	
Output Power at 1 dB Gain Compression		+14 dBm Typ	
Third Order Intercept		+24 dBm Typ	
Reverse Isolation		40 dB Typ	
Impedance		50 Ω Typ	
Bias Voltage	Vdd = +5 Vd	Vdd = +5 Vdc, Vgg = -5 Vdc	
Bias Conditions	ldd = 80 mA Typ,110 mA Max lgg = 1.0 mA Typ, 1.5 mA Max		

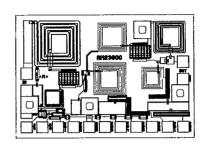
Maximum Ratings

Voltage	+7v@Vdd, -10v@Vgg	
Input Power	+20 dBm	
Storage Temperature	-65°C to +150°C	
Operating Temperature	-55°C to +125°C	

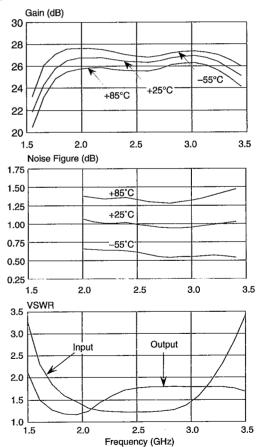
^{1. 100%} on-wafer tested.

Schematic





Typical Performance



Specifications Subject to Change Without Notice

Handling, Mounting and Bonding Procedures

MAAM23000

Handling

Permanent damage to the MAAM23000 may occur if the following precautions are not adhered to:

- A. Cleanliness The MAAM23000 should be handled in a clean environment. DO NOT attempt to clean assembly after the MAAM23000 is installed.
- B. Static Sensitivity --- All die handling equipment and personnel should comply with DOD-STD-1686 Class I.
- C. Transients Avoid instrument and power supply transients while bias is connected to the MAAM23000. Use shielded signal and bias cables to minimize inductive pick-up.
- D. General Handling DO NOT touch the surface of the die. It is recommended that the MAAM23000 die be handled along the long side with a sharp pair of tweezers.

Mounting

The MAAM23000 is back-metallized with Pd/Ni/Au (100/1,000/ 30,000Å) metallization. It can be die-mounted using Au/Sn eutectic preforms or a thermally and electrically conductive epoxy. The attachment surface should be clean and flat.

Eutectic Die Attach:

- A. An 80/20 Au/Sn preform is recommended with a work surface temperature of approximately 255°C and a tool temperature of 265°C. When hot 95/5 nitrogen/hydrogen gas is applied. solder temperature should be approximately 290°C.
- B. DO NOT expose the MAAM23000 to a temperature greater than 320°C for more than 20 seconds. No more than 3 seconds of scrubbing should be required for attachment.

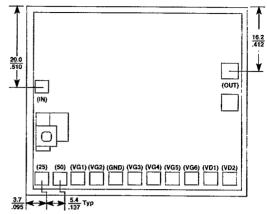
Epoxy Die Attach:

- A. Electrically conductive epoxy is required.
- B. Apply a minimum amount of epoxy and place the MAAM23000 into position. A thin epoxy fillet should be visible around the perimeter of the die.
- C. Cure epoxy per manufacturer's recommended schedule.

Bonding

- A. Ball or wedge bond with 1.0 mil diameter gold wire or 3.0 mil x 0.5 mil ribbon. Thermosonic bonding with a nominal stage temperature of 150°C and a ball bonding force of 40 to 50 grams or wedge bonding force of 18 to 22 grams is recommended. Ultrasonic energy and time should be adjusted to the minimum levels necessary to achieve reliable bonds.
- B. Bonds should be started on the die and terminated on the
- C. Bonding pads are 4.0 x 4.0 mils.

Outline

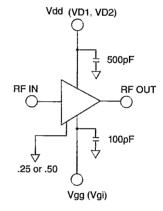


All dimensions are $\frac{\text{mils}}{\text{mm}}$

Die Size

0.061" X 0.043" X 0.004" (1.560mm X 1.080mm X 0.102mm)

Typical Bias Configuration



- 1. Nominal bias is obtained by grounding pad .50 and connecting Vgg to pad VG4.
- 2. Grounding pad .25, instead of pad .50, will decrease second stage current.
- Optional biasing can be obtained by connecting Vgg to pads VG1, VG2, VG3, VG5, or VG6, instead of VG4. Connecting to VG1 results in the lowest current; VG6 will yield the highest current. Adjusting the bias can customize performance to suit specia! requirements.